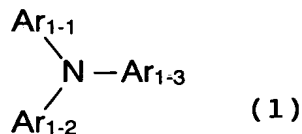


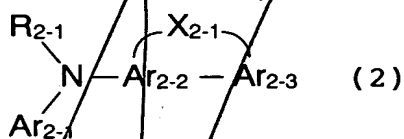
WHAT IS CLAIMED IS:

1. An electrophotographic photosensitive member, irradiated with semiconductor laser light having a wavelength of 380 to 500 nm, comprising:
 - a conductive substrate;
 - a charge-generating layer formed thereon; and
 - a charge transport layer formed thereon, the charge transport layer having a transmittance of at least 30% for the semiconductor laser light.
2. An electrophotographic photosensitive member according to claim 1, wherein the semiconductor laser light has a wavelength of 400 to 450 nm.
3. An electrophotographic photosensitive member according to claim 1, wherein the charge transport layer has a transmittance of 90% or more.
4. An electrophotographic photosensitive member according to claim 1, wherein the charge transport layer contains a charge transfer material represented by the following formula (1):



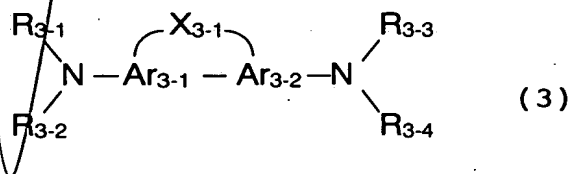
wherein Ar₁₋₁, Ar₁₋₂ and Ar₁₋₃ each is a substituted or unsubstituted aromatic group.

5. An electrophotographic photosensitive member according to claim 1, wherein the charge transport layer contains a charge transfer material represented by the following formula (2):



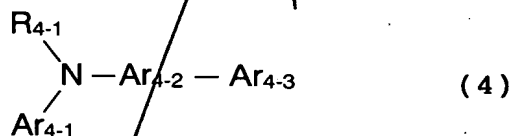
wherein Ar₂₋₁ is a substituted or unsubstituted aromatic group, Ar₂₋₂ and Ar₂₋₃ each is a substituted or unsubstituted aromatic group, R₂₋₁ is a substituted or unsubstituted alkyl group, a substituted or unsubstituted aralkyl group, a substituted or unsubstituted vinyl group, or a substituted or unsubstituted aromatic group, X₂₋₁ is a divalent organic group, and R₂₋₁ and Ar₂₋₁ may bond to each other to form a ring.

6. An electrophotographic photosensitive member according to claim 1, wherein the charge transport layer contains a charge transfer material represented by the following formula (3):



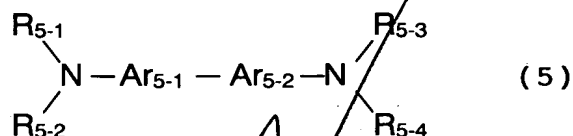
wherein Ar_{3-1} and Ar_{3-2} each is a substituted or unsubstituted aromatic group, R_{3-1} to R_{3-4} each is a substituted or unsubstituted alkyl group, a substituted or unsubstituted aralkyl group, a substituted or unsubstituted vinyl group, or a substituted or unsubstituted aromatic group wherein at least two of R_{3-1} to R_{3-4} are the substituted or unsubstituted aromatic groups, X_{3-1} is a divalent organic group, and R_{3-1} and R_{3-2} , or R_{3-3} and R_{3-4} may bond to each other to form a ring.

7. An electrophotographic photosensitive member according to claim 1 wherein the charge transport layer contains a charge transfer material represented by the following formula (4):



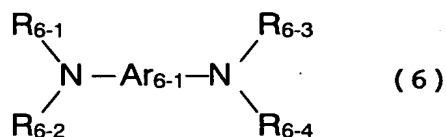
wherein Ar_{4-1} and Ar_{4-3} each is a substituted or unsubstituted aromatic group, Ar_{4-2} is a substituted or unsubstituted aromatic group, R_{4-1} is a substituted or unsubstituted alkyl group, a substituted or unsubstituted aralkyl group, a substituted or unsubstituted vinyl group, or a substituted or unsubstituted aromatic group, and Ar_{4-1} and R_{4-1} may bond to each other to form a ring.

8. An electrophotographic photosensitive member according to claim 1, wherein the charge transport layer contains a charge transfer material represented by the following formula (5):



wherein Ar_{5-1} and Ar_{5-2} each is a substituted or unsubstituted aromatic group, R_{5-1} to R_{5-4} each is a substituted or unsubstituted alkyl group, a substituted or unsubstituted aralkyl group, a substituted or unsubstituted vinyl group, or a substituted or unsubstituted aromatic group wherein at least two of R_{5-1} to R_{5-4} are the substituted or unsubstituted aromatic groups, and R_{5-1} and R_{5-2} or R_{5-3} and R_{5-4} may bond to each other to form a ring.

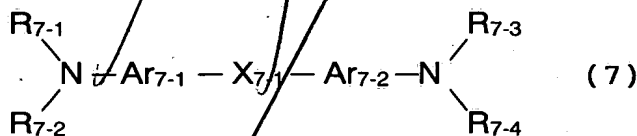
9. An electrophotographic photosensitive member according to claim 1, wherein the charge transport layer contains a charge transfer material represented by the following formula (6):



wherein Ar_{6-1} is a substituted or unsubstituted aromatic group, R_{6-1} to R_{6-4} each is a substituted or unsubstituted

alkyl group, a substituted or unsubstituted aralkyl group, a substituted or unsubstituted vinyl group, or a substituted or unsubstituted aromatic group wherein at least two of R_{6-1} to R_{6-4} are the substituted or unsubstituted aromatic groups, and R_{6-1} and R_{6-2} or R_{6-3} and R_{6-4} may bond to each other to form a ring.

10. An electrophotographic photosensitive member according to claim 1, wherein the charge transport layer contains a charge transfer material represented by the following formula (7):



wherein Ar_{7-1} and Ar_{7-2} each is a substituted or unsubstituted aromatic group, R_{7-1} to R_{7-4} each is a substituted or unsubstituted alkyl group, a substituted or unsubstituted aralkyl group, a substituted or unsubstituted vinyl group, or a substituted or unsubstituted aromatic group wherein at least two of R_{7-1} to R_{7-4} are the substituted or unsubstituted aromatic groups, R_{7-1} and R_{7-2} or R_{7-3} and R_{7-4} may bond to each other to form a ring, and X_{7-1} is a divalent organic group.

11. A process cartridge mountable to and detachable

Sub
A1

from an electrophotographic apparatus comprising:

an electrophotographic photosensitive member; and

at least one means selected from a charging means, a developing means and a cleaning means, the electrophotographic photosensitive member being integrally supported by said at least one means;

wherein the electrophotographic photosensitive member comprises a conductive substrate, a charge-generating layer formed thereon, and a charge transport layer formed thereon, the charge transport layer having a transmittance of at least 30% for the semiconductor laser light.

12. An electrophotographic apparatus comprising:

an electrophotographic photosensitive member;

a charging means;

an exposure means;

a developing means; and

a transfer means;

wherein the exposure means comprises a semiconductor laser having an oscillation wavelength of 380 to 500 nm as an exposure light source, and

the electrophotographic photosensitive member comprises a conductive substrate, a charge-generating layer formed thereon, and a charge transport layer formed thereon, the charge transport layer having a transmittance of at least

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30% for the semiconductor laser light.

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